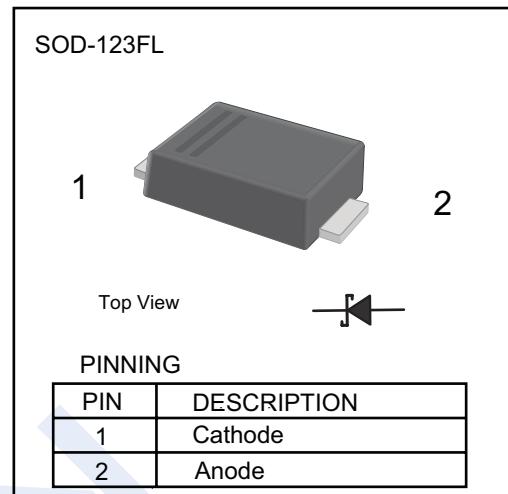


Schottky Diodes

SS22FL ~ SS220FL

■ Features

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications



■ Absolute Maximum Ratings Ta = 25°C unless otherwise specified

Parameter	Symbol	SS 22FL	SS 24FL	SS 26FL	SS 28FL	SS 210FL	SS 212FL	SS 215FL	SS 220FL	Unit			
Repetitive Peak Reverse Voltage	V _{RRM}	20	40	60	80	100	120	150	200	V			
Surge Peak Reverse Voltage	V _{RSM}	14	28	42	56	70	84	105	140				
Maximum DC Blocking Voltage	V _{DC}	20	40	60	80	100	120	150	200				
Averaged Forward Current	I _O	2							A				
Peak forward surge current	I _{FSM}	50			40								
Instantaneous Forward Voltage at 2A	V _F	0.55		0.7		0.85		0.95		V			
Maximum DC Reverse Current T _A =25°C at rated DC blocking voltage T _A =100°C	I _{R66}	0.5		3		0.3				mA			
Typical Junction Capacitance *1	C _j	220		80						pF			
Typical thermal resistance *2	R _{thJA}	65							°C/W				
Junction Temperature	T _j	125							°C				
Storage Temperature	T _{stg}	-55 to 150											

* 1 Measured at 1MHz and applied reverse voltage of 4V D.C

* 2 P.C.B. mounted with 2" × 2" (5×5 cm) copper pad areas.

■ Marking

NO.	SS22FL	SS24FL	S26FL	SS28FL	SS210FL	SS212FL	SS215FL	SS220FL
Marking	S22	S24	S26	S28	S210	S212	S215	S220

Schottky Diodes

SS22FL ~ SS220FL

■ Typical Characteristics

Fig.1 Forward Current Derating Curve

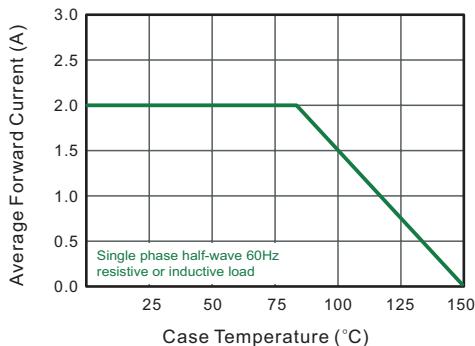


Fig.2 Typical Reverse Characteristics

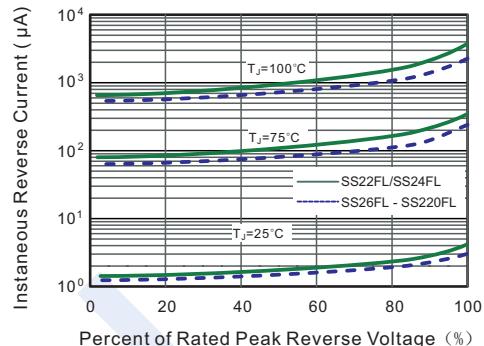


Fig.3 Typical Forward Characteristic

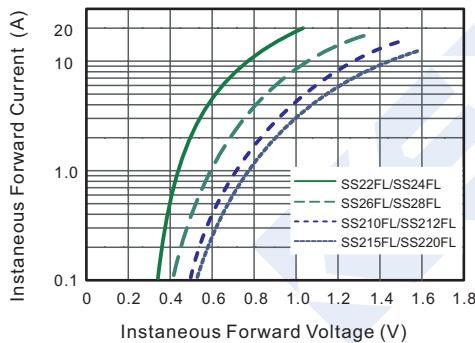


Fig.4 Typical Junction Capacitance

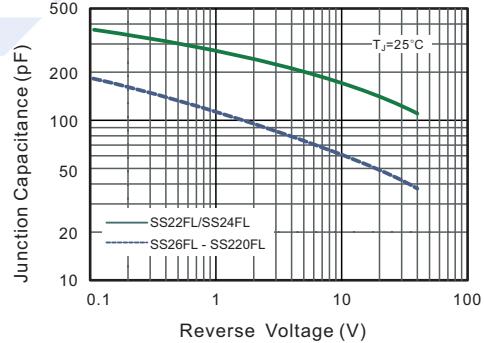


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

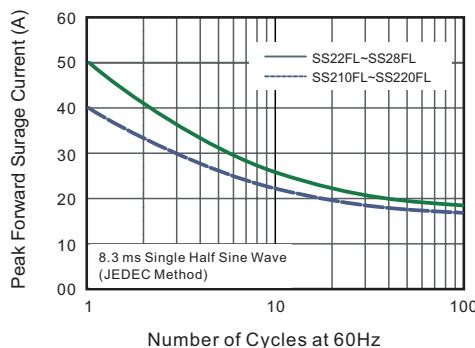
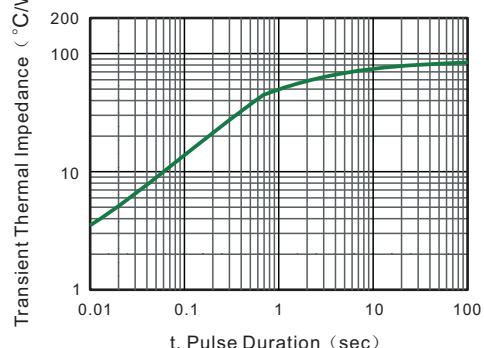


Fig.6- Typical Transient Thermal Impedance



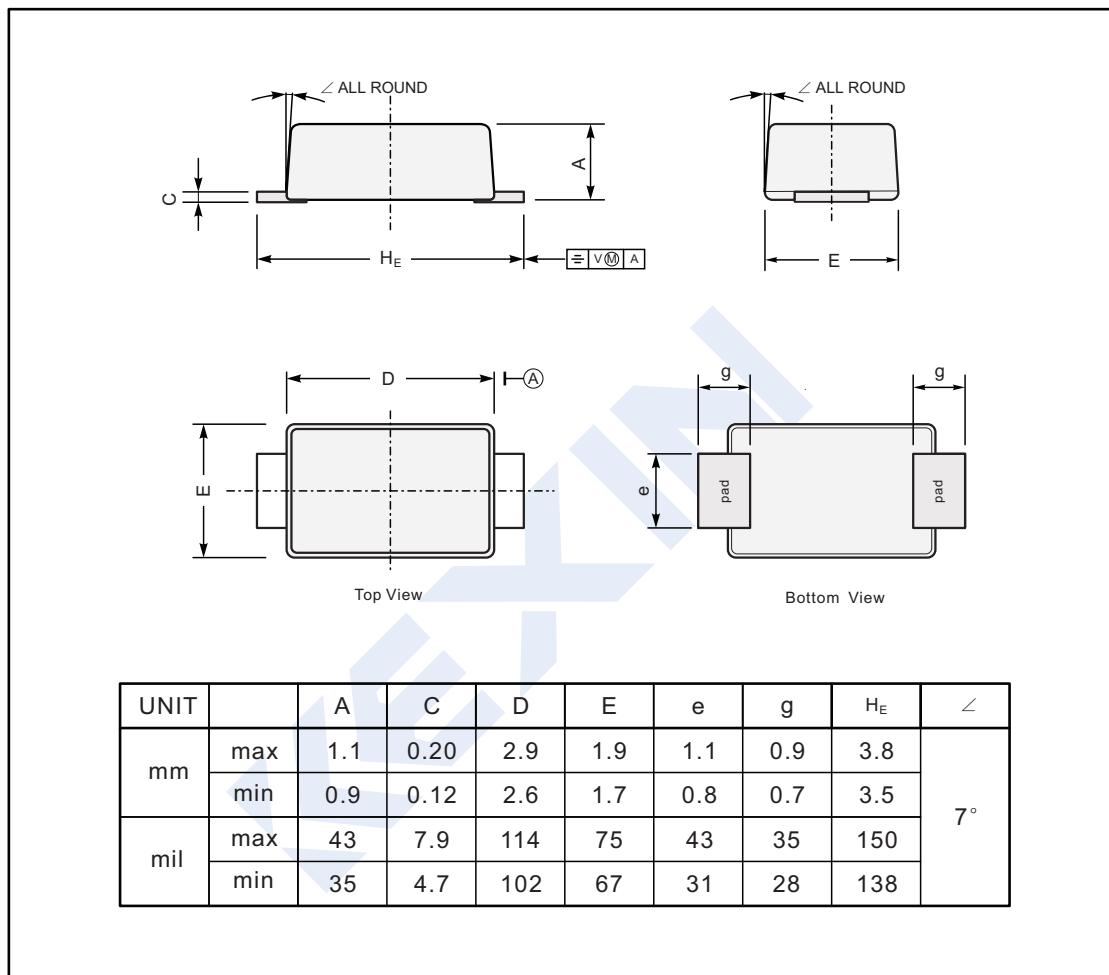
Schottky Diodes

SS22FL ~ SS220FL

■ Package Outline Dimensions

Plastic surface mounted package; 2 leads

SOD-123FL



■ The Recommended Mounting Pad Size

